

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,958,526 B2
DATED : October 25, 2005
INVENTOR(S) : Stephen M. Gates et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 1.

Lines 45-46, should read -- Prior art inductor structures used in RF and microwave circuits are commonly isolated from ground using SiO_2 which has a dielectric constant (k) of 4 to 4.2. Prior art inductors may be passivated with a polymer dielectric (e.g. Polyimide) which has a dielectric constant (k) of about 2.9. --.

Line 66, "RE" should read -- RF --.

Column 11.

Line 26, "surf ice" should read -- surface --.

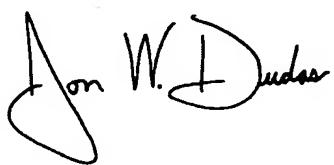
Line 40, "The electronic Structure of" should read -- The electronic structure of --.

Column 12.

Line 24, "containing lees C" should read -- containing less than C --.

Signed and Sealed this

Second Day of May, 2006



JON W. DUDAS
Director of the United States Patent and Trademark Office